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# Onsemi

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# Single Schmitt-Trigger Inverter

The NLU1G14 MiniGate<sup>™</sup> is an advanced high-speed CMOS Schmitt-trigger inverter in ultra-small footprint.

The NLU1G14 input and output structures provide protection when voltages up to 7.0 V are applied, regardless of the supply voltage.

The NLU1G14 can be used to enhance noise immunity or to square up slowly changing waveforms.

## Features

- High Speed:  $t_{PD} = 4.0 \text{ ns} (Typ) @ V_{CC} = 5.0 \text{ V}$
- Low Power Dissipation:  $I_{CC} = 1 \mu A$  (Max) at  $T_A = 25^{\circ}C$
- Power Down Protection Provided on inputs
- Balanced Propagation Delays
- Overvoltage Tolerant (OVT) Input and Output Pins
- Ultra-Small Packages
- These are Pb-Free Devices

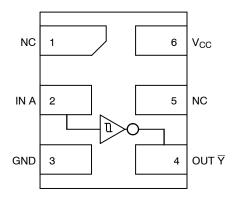


Figure 1. Pinout (Top View)

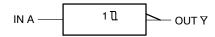


Figure 2. Logic Symbol

PIN ASSIGNMENT				
1	NC			
2	IN A			
3	GND			
4	OUT Y			
5	NC			
6	V <sub>CC</sub>			

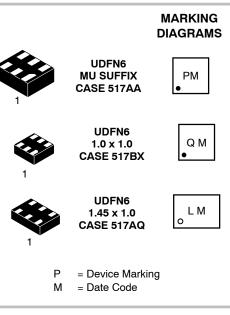
#### FUNCTION TABLE

А	Y
L	H
H	L



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#### ORDERING INFORMATION

See detailed ordering and shipping information on page 4 of this data sheet.

#### MAXIMUM RATINGS

Symbol	Parameter		Value	Unit
V <sub>CC</sub>	DC Supply Voltage		-0.5 to +7.0	V
V <sub>IN</sub>	DC Input Voltage		-0.5 to +7.0	V
V <sub>OUT</sub>	DC Output Voltage		-0.5 to +7.0	V
I <sub>IK</sub>	DC Input Diode Current V	<sub>IN</sub> < GND	-20	mA
Ι <sub>ΟΚ</sub>	DC Output Diode Current V <sub>O</sub>	<sub>JT</sub> < GND	±20	mA
Ι <sub>Ο</sub>	DC Output Source/Sink Current		±12.5	mA
I <sub>CC</sub>	DC Supply Current Per Supply Pin		±25	mA
I <sub>GND</sub>	DC Ground Current per Ground Pin		±25	mA
T <sub>STG</sub>	Storage Temperature Range		-65 to +150	°C
ΤL	Lead Temperature, 1 mm from Case for 10 Seconds		260	°C
TJ	Junction Temperature Under Bias		150	°C
MSL	Moisture Sensitivity		Level 1	
F <sub>R</sub>	Flammability Rating Oxygen Index	: 28 to 34	UL 94 V-0 @ 0.125 in	
V <sub>ESD</sub>	ESD Withstand Voltage Human Body Mode Machine Mode Charged Device Mode	l (Note 3)	> 2000 > 200 N/A	V
ILATCHUP	Latchup Performance Above $V_{CC}$ and Below GND at 125°C (	Note 5)	±500	mA

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected. 1. Measured with minimum pad spacing on an FR4 board, using 10 mm-by-1 inch, 2 ounce copper trace no air flow.

2. Tested to EIA / JESD22-A114-A.

Tested to EIA / JESD22-A115-A.
 Tested to JESD22-C101-A.

5. Tested to EIA / JESD78.

#### **RECOMMENDED OPERATING CONDITIONS**

Symbol	Parameter	Min	Max	Unit	
V <sub>CC</sub>	Positive DC Supply Voltage	1.65	5.5	V	
V <sub>IN</sub>	Digital Input Voltage		0	5.5	V
V <sub>OUT</sub>	Output Voltage		0	5.5	V
T <sub>A</sub>	Operating Free-Air Temperature		-55	+125	°C
$\Delta t/\Delta V$	Input Transition Rise or Fall Rate $V_{CC}$ = 3.3 V ± $V_{CC}$ = 5.0 V ±	0.3 V 0.5 V	0 0	No Limit No Limit	ns/V

## DC ELECTRICAL CHARACTERISTICS

			V <sub>CC</sub>		T <sub>A</sub> = 25 °C	;	T <sub>A</sub> = +85°C		T <sub>A</sub> = −55°C to +125°C			
Symbol	Parameter	Conditions	(V)	Min	Тур	Max	Min	Max	Min	Max	Unit	
V <sub>T+</sub>	Positive Threshold Voltage		3.0 4.5 5.5	1.85 2.86 3.50	2.0 3.0 3.6	2.2 3.15 3.85		2.2 3.15 3.85		2.2 3.15 3.85	V	
V <sub>T-</sub>	Negative Threshold Voltage		3.0 4.5 5.5	0.9 1.35 1.65	1.5 2.3 2.9	1.65 2.46 3.05	0.9 1.35 1.65		0.9 1.35 1.65		V	
V <sub>H</sub>	Hysteresis Voltage		3.0 4.5 5.5	0.30 0.40 0.50	0.57 0.67 0.74	1.20 1.40 1.60	0.30 0.40 0.50	1.20 1.40 1.60	0.30 0.40 0.50	1.20 1.40 1.60	V	
V <sub>OH</sub>	Minimum High–Level Output	$V_{IN} \le V_{T-MIN}$ $I_{OH}$ = -50 µA	2.0 3.0 4.5	1.9 2.9 4.4	2.0 3.0 4.5		1.9 2.9 4.4		1.9 2.9 4.4		V	
	Voltage	$\begin{array}{l} V_{IN} \leq V_{T-MIN} \\ I_{OH} = -4 \text{ mA} \\ I_{OH} = -8 \text{ mA} \end{array}$	3.0 4.5	2.58 3.94			2.48 3.80		2.34 3.66			
V <sub>OL</sub>	Maximum Low-Level Output	$V_{IN} \ge V_{T+MAX}$ $I_{OL} = 50 \ \mu A$	2.0 3.0 4.5		0 0 0	0.1 0.1 0.1		0.1 0.1 0.1		0.1 0.1 0.1	V	
	Voltage	$\begin{array}{l} V_{IN} \geq V_{T+MAX} \\ I_{OL} = 4 \mbox{ mA} \\ I_{OL} = 8 \mbox{ mA} \end{array}$	3.0 4.5			0.36 0.36		0.44 0.44		0.52 0.52		
I <sub>IN</sub>	Input Leakage Current	$0 \le V_{IN} \le 5.5 V$	0 to 5.5			±0.1		±1.0		±1.0	μΑ	
I <sub>CC</sub>	Quiescent Supply Current	V <sub>IN</sub> = 5.5 V or GND	5.5			1.0		10		40	μΑ	

#### AC ELECTRICAL CHARACTERISTICS (Input $t_r = t_f = 3.0 \text{ ns}$ )

		V <sub>cc</sub>	Test		T <sub>A</sub> = 25 °	с	T <sub>A</sub> =	+85°C	T <sub>A</sub> = -5 +12		
Symbol	Parameter	(V)	Condition	Min	Тур	Max	Min	Max	Min	Max	Unit
t <sub>PLH</sub> ,	Propagation Delay,	3.0 to	C <sub>L</sub> = 15 pF		7.0	12.8	1.0	15.0	1.0	17.0	ns
t <sub>PHL</sub>	Input A to Output Y	3.6	C <sub>L</sub> = 50 pF		8.5	16.3	1.0	18.5	1.0	20.5	
		4.5 to	C <sub>L</sub> = 15 pF		4.0	8.6	1.0	10.0	1.0	11.5	
		5.5	C <sub>L</sub> = 50 pF		5.5	10.6	1.0	12.0	1.0	13.5	
C <sub>IN</sub>	Input Capacitance				5	10		10		10.0	pF
C <sub>PD</sub>	Power Dissipation Capacitance (Note 6)	5.0			7.0						pF

6.  $C_{PD}$  is defined as the value of the internal equivalent capacitance which is calculated from the dynamic operating current consumption without load. Average operating current can be obtained by the equation  $I_{CC(OPR)} = C_{PD} \bullet V_{CC} \bullet f_{in} + I_{CC}$ .  $C_{PD}$  is used to determine the no-load dynamic power consumption:  $P_D = C_{PD} \bullet V_{CC}^2 \bullet f_{in} + I_{CC} \bullet V_{CC}$ .

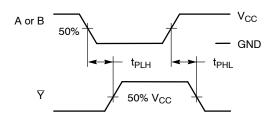
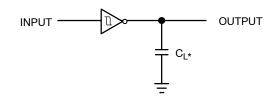


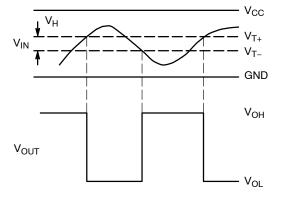
Figure 3. Switching Waveforms

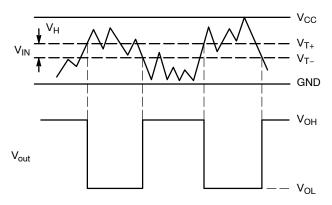


\*Includes all probe and jig capacitance.

A 1-MHz square input wave is recommended for propagation delay tests.







(a) A Schmitt-Trigger Squares Up Inputs With Slow Rise and Fall Times

(b) A Schmitt-Trigger Offers Maximum Noise Immunity

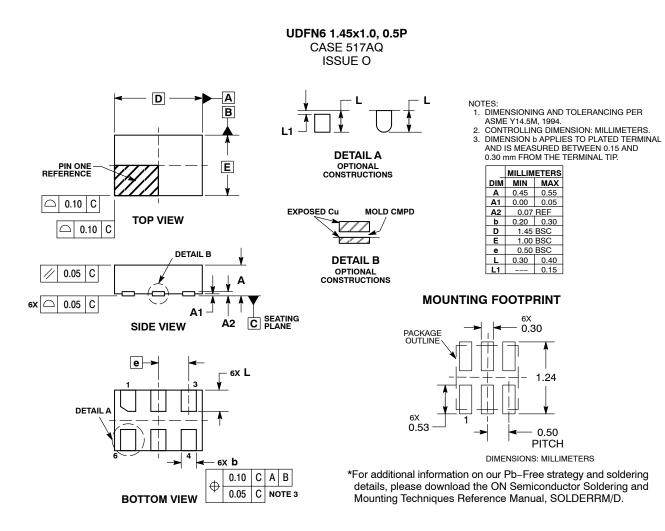
#### Figure 5. Typical Schmitt-Trigger Applications

#### **ORDERING INFORMATION**

Device	Package	Shipping <sup>†</sup>
NLU1G14MUTCG	UDFN6, 1.2 x 1.0, 0.4P (Pb-Free)	3000 / Tape & Reel
NLU1G14AMUTCG	UDFN6, 1.45 x 1.0, 0.5P (Pb–Free)	3000 / Tape & Reel
NLU1G14CMUTCG	UDFN6, 1.0 x 1.0, 0.35P (Pb-Free)	3000 / Tape & Reel

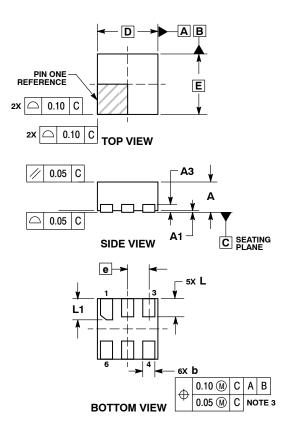
†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

#### PACKAGE DIMENSIONS



#### PACKAGE DIMENSIONS

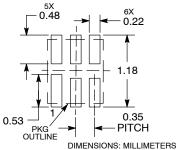
UDFN6 1.0x1.0, 0.35P CASE 517BX ISSUE O



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  ASME Y14.5M, 1994.
  CONTROLLING DIMENSION: MILLIMETERS.
  DIMENSION & APPLIES TO PLATED TERMINAL AND IS MEASURED BETWEEN 0.15 AND 0.20 MM FROM TERMINAL TIP.
  PACKAGE DIMENSIONS EXCLUSIVE OF BURRS AND MOLD FLASH.

BUF	BURRS AND MOLD FL							
		MILLIMETERS						
DI	Λ	MIN	MAX					
Α		0.45	0.55					
A1		0.00	0.05					
A3	;	0.13	0.13 REF					
b		0.12 0.22						
D		1.00 BSC						
E		1.00	1.00 BSC					
е		0.35 BSC						
L		0.25	0.35					
L1		0.30	0.40					

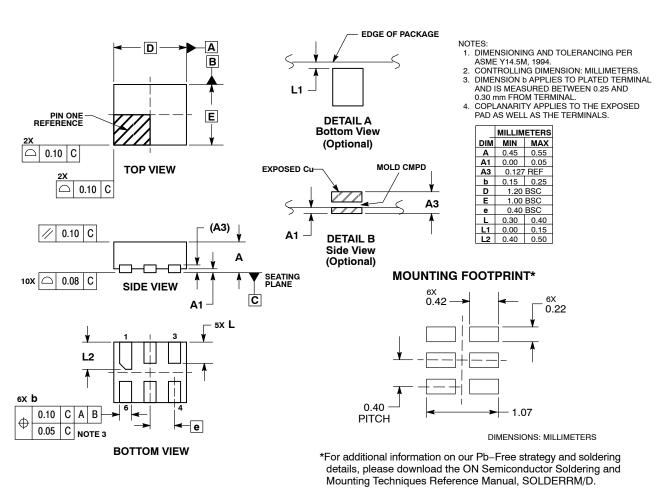
# RECOMMENDED SOLDERING FOOTPRINT\*



\*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

#### PACKAGE DIMENSIONS

UDFN6, 1.2x1.0, 0.4P CASE 517AA ISSUE D



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